Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

0.110 inches

Terminal Length:

1.000 inches

Overall Diameter:

0.110 inches

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Germanium

Voltage Rating In Volts Per Characteristic:

72.0 peak-point voltage

Current Rating Per Characteristic:

10.00 milliamperes forward current, average peak and 5.00 milliamperes source cutoff current preset

Capacitance Rating In Picofarads:

5.0

Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius ambient air

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

2 uninsulated wire lead

Specification Data:

81349-mil-s-19500/269 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0